

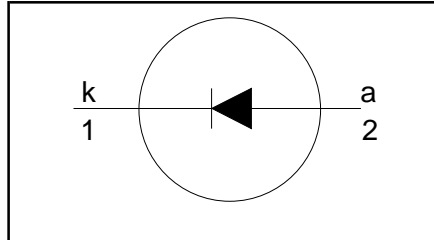
## Rectifier diodes ultrafast

**BYV29-600**

### FEATURES

- Low forward volt drop
- Fast switching
- Soft recovery characteristic
- High thermal cycling performance
- Low thermal resistance

### SYMBOL



### QUICK REFERENCE DATA

$$V_R = 600V$$

$$V_F \leq 1.03 V$$

$$I_{F(AV)} = 9 A$$

$$t_{rr} \leq 60 ns$$

### GENERAL DESCRIPTION

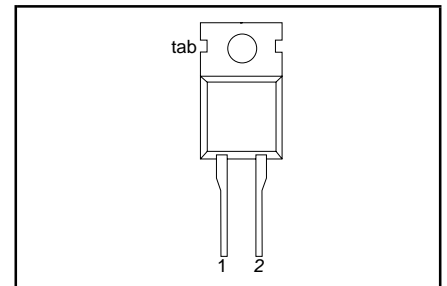
Ultra-fast, epitaxial rectifier diodes intended for use as output rectifiers in high frequency switched mode power supplies.

The BYV29-600 is supplied in the conventional leaded SOD59 (TO220AC) package.

### PINNING

PIN	DESCRIPTION
1	cathode
2	anode
tab	cathode

### SOD59 (TO220AC)



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	Peak repetitive reverse voltage	square wave; $\delta = 0.5$ ; $T_{mb} \leq 120^\circ C$ $t = 25 \mu s$ ; $\delta = 0.5$ ; $T_{mb} \leq 120^\circ C$ $t = 10 ms$ $t = 8.3 ms$ sinusoidal; with reapplied $V_{RRM(max)}$	-	600	V
$V_{RWM}$	Crest working reverse voltage		-	600	V
$V_R$	Continuous reverse voltage		-	600	V
$I_{F(AV)}$	Average forward current <sup>1</sup>		-	9	A
$I_{FRM}$	Repetitive peak forward current		-	18	A
$I_{FSM}$	Non-repetitive peak forward current.		-	70	A
			-	77	A
$T_{stg}$	Storage temperature		-40	150	$^\circ C$
$T_j$	Operating junction temperature		-	150	$^\circ C$

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th j-mb}$	Thermal resistance junction to mounting base	in free air.	-	-	2.5	K/W
$R_{th j-a}$	Thermal resistance junction to ambient		-	60	-	K/W

<sup>1</sup> Neglecting switching and reverse current losses.

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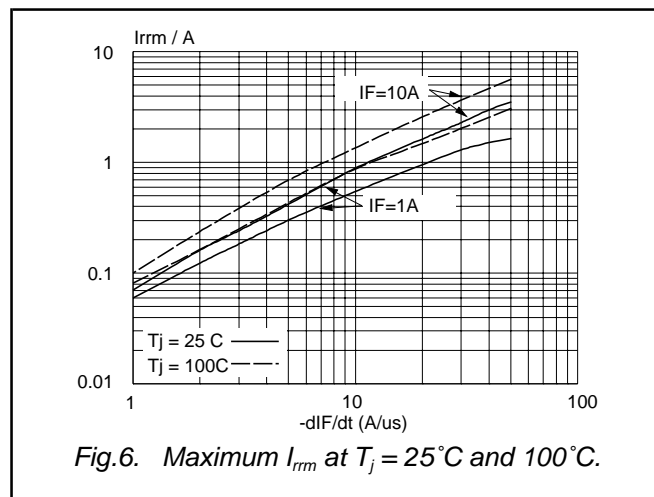
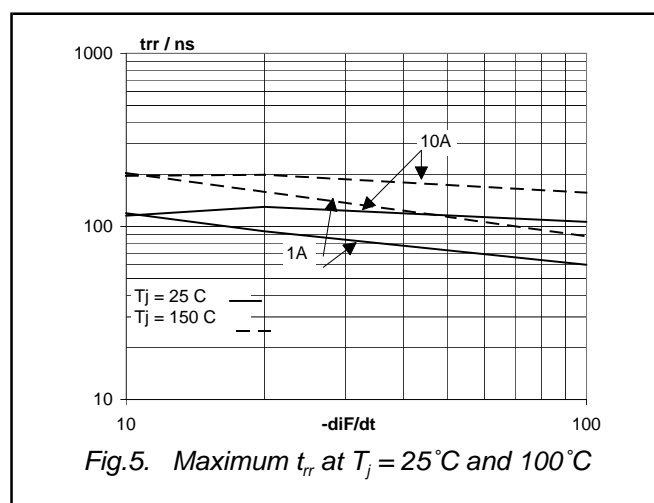
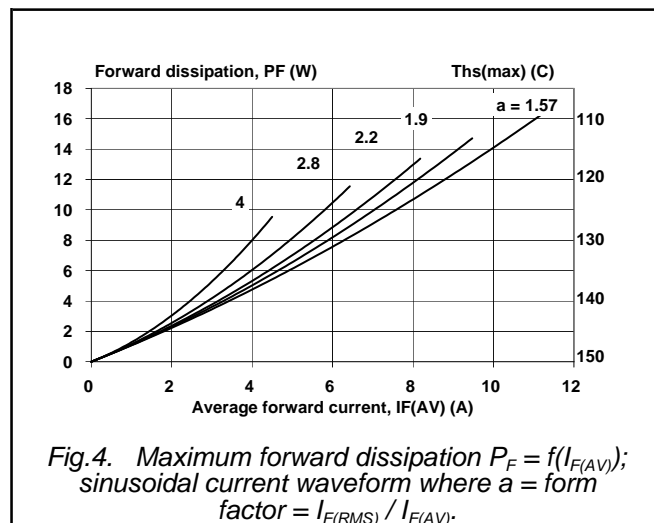
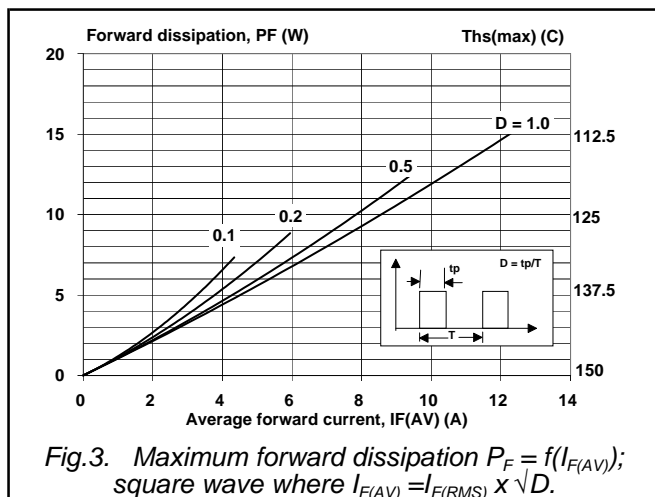
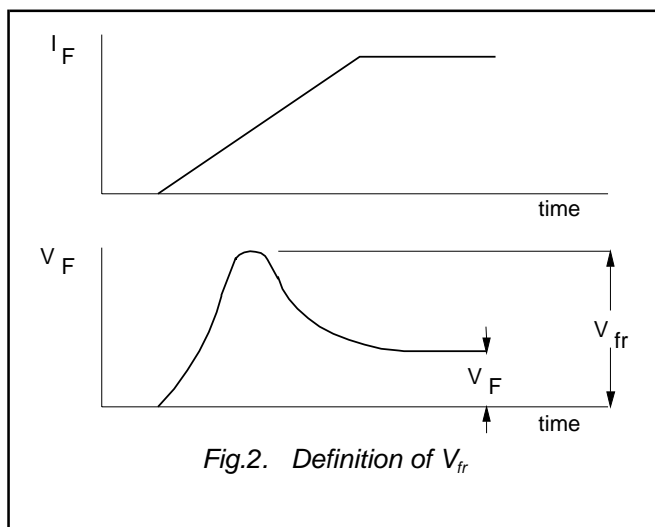
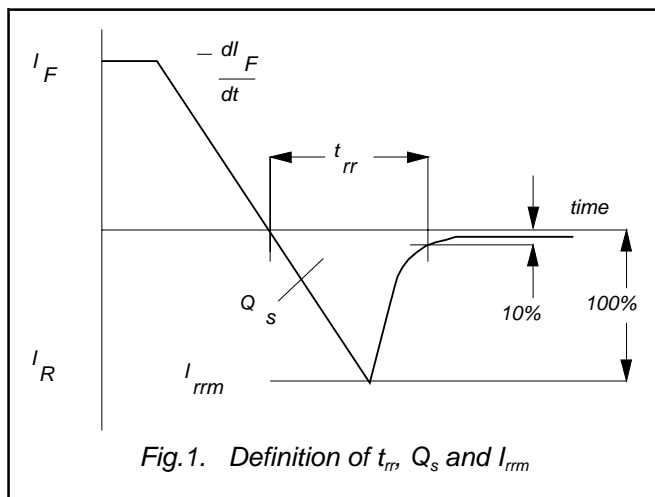
## ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ }^{\circ}\text{C}$  unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 8\text{ A}$ ; $T_j = 150\text{ }^{\circ}\text{C}$	-	0.90	1.03	V
		$I_F = 8\text{ A}$	-	1.05	1.25	V
		$I_F = 20\text{ A}$	-	1.30	1.45	V
$I_R$	Reverse current	$V_R = V_{RRM}$	-	2.0	50	$\mu\text{A}$
		$V_R = V_{RRM}$ ; $T_j = 100\text{ }^{\circ}\text{C}$	-	0.1	0.35	mA
$Q_s$	Reverse recovery charge	$I_F = 2\text{ A}$ to $V_R \geq 30\text{ V}$ ; $dI_F/dt = 20\text{ A}/\mu\text{s}$	-	40	70	nC
$t_{rr}$	Reverse recovery time	$I_F = 1\text{ A}$ to $V_R \geq 30\text{ V}$ ; $dI_F/dt = 100\text{ A}/\mu\text{s}$	-	50	60	ns
$I_{rrm}$	Peak reverse recovery current	$I_F = 10\text{ A}$ to $V_R \geq 30\text{ V}$ ; $dI_F/dt = 50\text{ A}/\mu\text{s}$ ; $T_j = 100\text{ }^{\circ}\text{C}$	-	3.0	5.5	A
$V_{fr}$	Forward recovery voltage	$I_F = 10\text{ A}$ ; $dI_F/dt = 10\text{ A}/\mu\text{s}$	-	3.2	-	V

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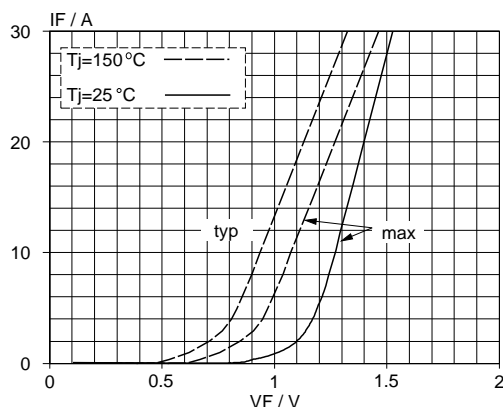


Fig.7. Typical and maximum forward characteristic  
 $I_F = f(V_F)$ ; parameter  $T_j$

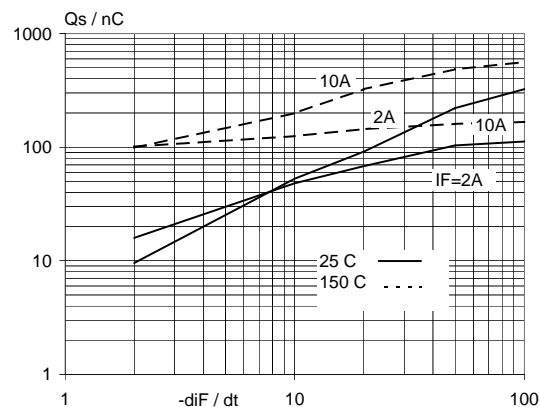


Fig.9. Maximum  $Q_s$  at  $T_j = 25^\circ\text{C}$

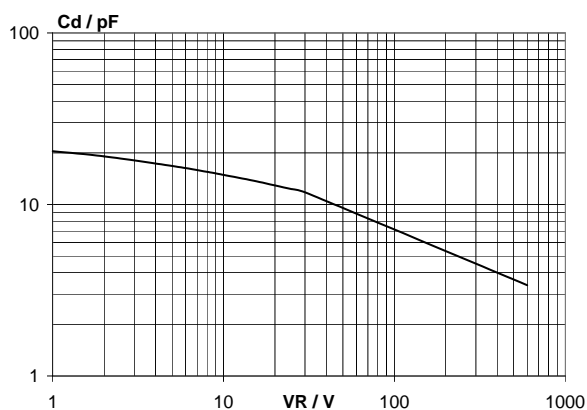


Fig.8. Typical junction capacitance  $C_d$  at  $f = 1\text{ MHz}$ ;  
 $T_j = 25^\circ\text{C}$

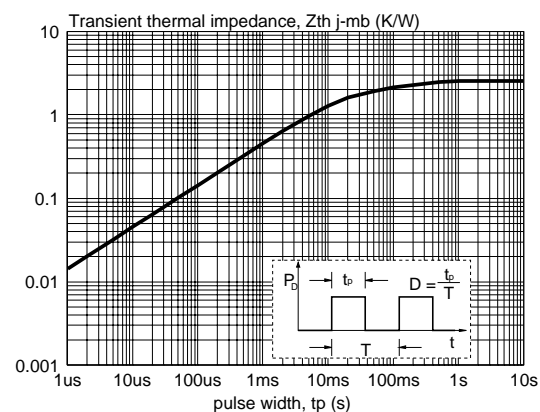
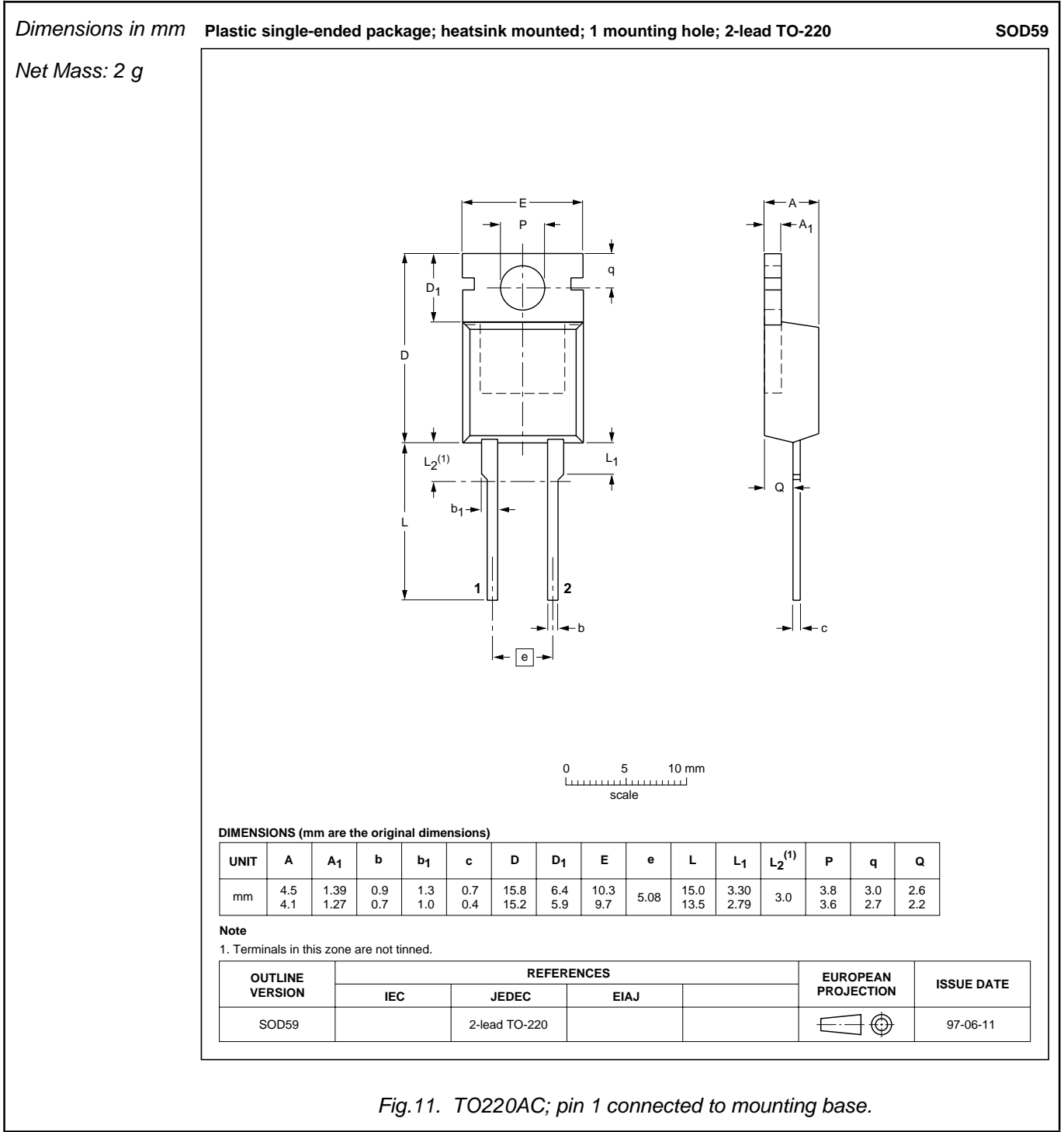


Fig.10. Transient thermal impedance  $Z_{th\ j-mb} = f(t_p)$

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MECHANICAL DATA



Notes

1. Refer to mounting instructions for TO220 envelopes.
2. Epoxy meets UL94 V0 at 1/8".

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### DEFINITIONS

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	
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